# 2SB791(K)

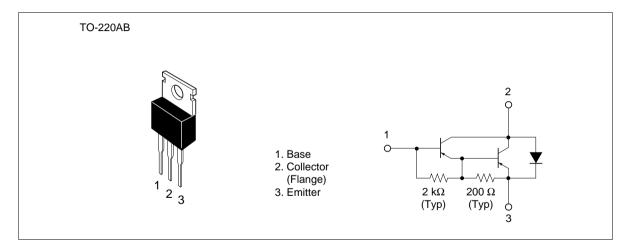
## Silicon PNP Epitaxial

# **HITACHI**

### **Application**

Medium speed and power switching complementary pair with 2SD970(K)

#### Outline



### **Absolute Maximum Ratings** ( $Ta = 25^{\circ}C$ )

Item	Symbol	Rating	Unit
Collector to base voltage	$V_{\text{CBO}}$	-120	V
Collector to emitter voltage	V <sub>CEO</sub>	-120	V
Emitter to base voltage	$V_{EBO}$	<b>-</b> 7	V
Collector current	I <sub>c</sub>	-8	A
Collector peak current	I <sub>C(peak)</sub>	-12	A
Collector power dissipation	P <sub>c</sub> *1	40	W
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

Note: 1. Value at  $T_c = 25^{\circ}C$ 

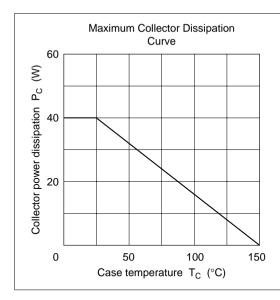


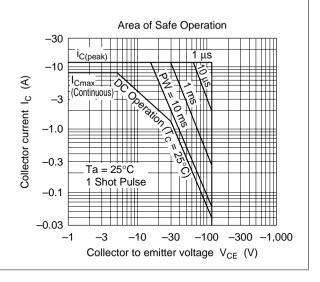
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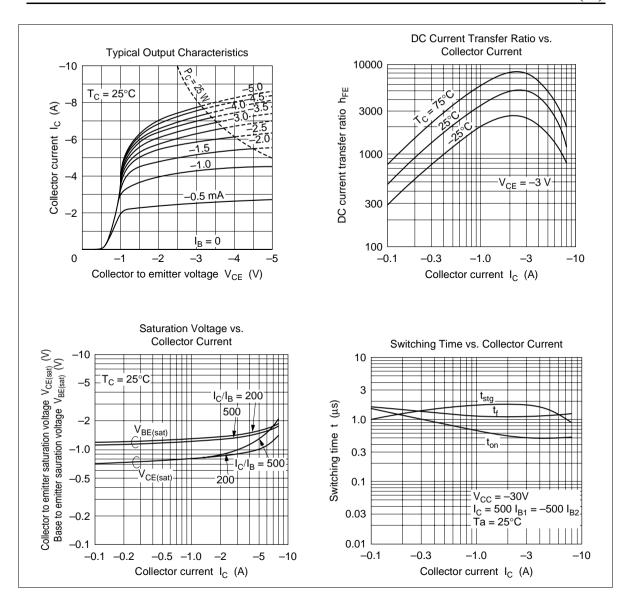
### **Electrical Characteristics** (Ta = 25°C)

Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	-120	_	_	V	$I_{\text{C}}$ = -25 mA, $R_{\text{BE}}$ = $\infty$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	<b>-7</b>	_	_	V	$I_{E} = -50 \text{ mA}, I_{C} = 0$
Collector cutoff current	I <sub>CBO</sub>	_	_	-100	μΑ	$V_{CB} = -120 \text{ V}, I_{E} = 0$
	I <sub>CEO</sub>	_	_	-10	μΑ	$V_{CE} = -100 \text{ V}, R_{BE} = \infty$
DC current transfer ratio	h <sub>FE</sub>	1000	_	20000		$V_{CE} = -3 \text{ V}, I_{C} = -4 \text{ A}^{*1}$
Collector to emitter saturation	V <sub>CE(sat)(1)</sub>	_	_	-1.5	V	$I_{\rm C} = -4 \text{ A}, I_{\rm B} = -8 \text{ mA}^{*1}$
voltage	V <sub>CE(sat)(2)</sub>	_	_	-3.0	V	$I_{\rm C} = -8 \text{ A}, I_{\rm B} = -80 \text{ mA}^{*1}$
Base to emitter saturation	$V_{BE(sat)(1)}$	_	_	-2.0	V	$I_{\rm C} = -4 \text{ A}, I_{\rm B} = -8 \text{ mA}^{*1}$
voltage	$V_{BE(sat)(2)}$	_	_	-3.5	V	$I_{\rm C} = -8 \text{ A}, I_{\rm B} = -80 \text{ mA}^{*1}$
Turn on time	t <sub>on</sub>	_	0.5	_	μs	$I_{\rm C} = -4 \text{ A}, I_{\rm B1} = I_{\rm B2} = -8 \text{ mA}$
Storage time	t <sub>stg</sub>	_	1.6	_	μs	_
Fall time	t <sub>f</sub>	_	1.5	_	μs	_

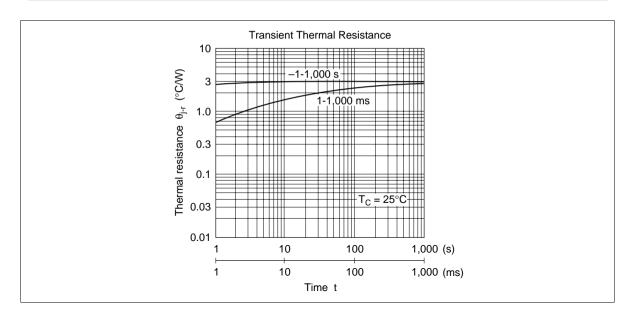
Note: 1. Pulse test



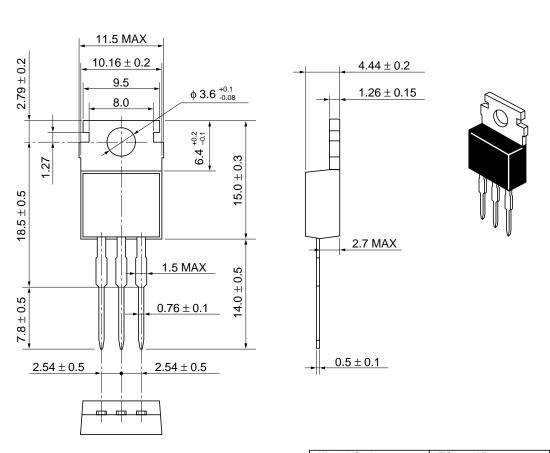




## 2SB791(K)



Unit: mm



Hitachi Code	TO-220AB
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	1.8 g

#### **Cautions**

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